HAMAMATSU

WIDE DYNAMIC RANGE MICROCHANNEL PLATES F6584 SERIES

20 µA Output Current is Available *

The F6584 series is a wide dynamic range MCP that offers more than ten - fold increase in maximum output current compared to conventional MCPs. This increased current capability is due to low plate resistance. When operated in pulse counting mode, the F6584 series MCPs also provide maximum counting capability that is more than ten - fold higher than conventional MCPs. The design is optimized to prevent resistance reduction resulting from high power consumption or high temperature operation.

The F6584 series MCPs therefore offer excellent stability and reliability even during high current or high temperature operations. This results in a very wide dynamic range, making these MCPs ideal for various applications such as mass spectrometers and usage for high counting PMTs.

FEATURES

- Wide Dynamic Range Typ. 20 µA Maximum Output Current *
- Operable in high temperature condition (+350°C Max. ©)
- High Gain and Low Noise

 * When the MCP resistance is less than 10 M $\!\Omega.$

APPLICATIONS

● MS Detector● GC-MS● LC-MS

● ESCA
■ Mössbauer Detector

SPECIFICATIONS

GENERAL

Parameter	F6584-01	F6584-09	Unit
Outer Diameter	24.9		mm
Effective Diameter	20		mm
Plate Thickness	0.48	0.43	mm
Channel Diameter	12	10	μm
Channel Pitch	15	12	μm
Bias Angle	5,15		degree
Open Area Ratio	60		%
Electrode Material	Inconel		_

CHARACTERISTICS (at 1000V, 1.3×10⁻⁴ Pa(1×10⁻⁶ Torr), +25°C)

Gain	More than 104	-
Plate Resistance	2 to 30	$M\Omega$
Maximum Dark Current	5 × 10 ⁻¹³	A/cm ²
Maximum Linear Output Signal	10 to 20% of the strip current ^(a)	-

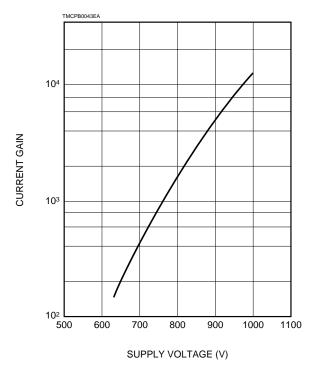
MAXIMUM RATINGS (Absolute Values)

Supply Voltage [®]	1000	V
Ambient Temperature ©	-50 to +350	°C

NOTE: (a): The strip current is the current flowing through the channel walls, which supplies the current released from the channel walls. It is given by: Supply voltage / Plate resistance.

- **b**: At a vacuum of 1.3×10^{-4} Pa(1×10^{-6} Torr) or less.
- ©: Single plate operation

Figure 1: Typical Current Gain vs. Supply Voltage

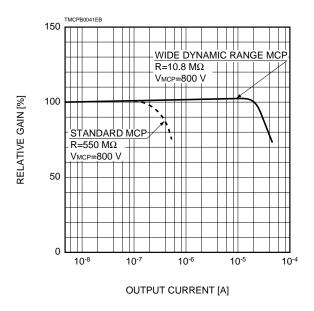


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Figure 2: MCP Saturation Characteristics (D.C. MODE)



STANDARD MCP
RESISTANCE:
400 MΩ/2 STAGE MCP
GAIN: 5×106

105

GAIN: 8×106

10-7

Figure 3: MCP Saturation Characteristics (COUNTING MODE)

TMCPB0042EC

10⁸

10

OUTPUT CHARGE (C/s)

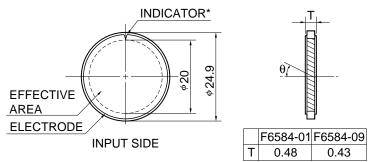
10-6

F6584 WIDE DYNAMIC RANGE MCP RESISTANCE : 22.4 MΩ/ 2 STAGE MCP

10-5

10-4

Figure 4: MCP Dimensional Outline (Unit: mm)



θ: Bias Angle

TMCPA0030EE

PRECAUTIONS FOR USE

- Avoid touching the MCP or MCP assembly with bare hands.
- Handle the MCP only in a clean room since dust and humidity may adversely affect MCP characteristics.
- The MCP should be operated in vacuum below 1.33 x 10⁻⁴ Pa(1 × 10⁻⁶ torr).
- The MCP should be kept in vacuum or dry nitrogen gas atmosphere during long periods of storage.
- When outgassing from the MCP occurs, baking the MCP at 400°C maximum in a vacuum system is recommended. In addition electron bombarding may be effective.

HAMAMATSU

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^{*}This indicator shows the MCP input side and the direction of channel bias.